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**PHH 454**

**II Semester M.Sc. Degree Examination, September/October 2022**

**PHYSICS**

**Condensed Matter Physics and Electronics**

Time : 3 Hours

Max. Marks : 70

**Note :** Answer **any four** questions choosing **one each** from Parts I–V and Part V is **compulsory**.

**PART – I**

1. a) Define the crystal lattice. Explain the face centered cubic unit cell.
- b) Show that the interplanar spacing of a cubic centre lattice with Miller indices (hkl) is given by :

$$d_{hkl} = \frac{a}{(h^2 + k^2 + l^2)^{1/2}}$$

Calculate the interplanar spacing for planes (321), (210) and (111) in a cubic lattice with  $a = 5.62 \text{ \AA}$ . **(8+7)**

2. a) Explain X-ray scattering by an atom, electron and unit cell.
- b) What is the lattice vibration ? Obtain the dispersion relation for one dimensional diatomic lattice. **(7+8)**

**PART – II**

3. a) Describe the behavior of electrons in three dimensional potential well.
- b) Write an expression for Fermi energy and explain it at various temperature. **(8+7)**
4. a) Obtain an expression for Fermi energy in an intrinsic semiconductor.
- b) Write notes on :
  - i) Failures of free electron model and
  - ii) Electrical conductivity in semiconductor. **(7+8)**

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## PART – III

5. a) Discuss the characteristics of LCR circuit and justify why there is phase difference between current and voltage.

b)  $f(t) = \begin{cases} 0 & -T/2 < t < 0 \\ \lambda & 0 < t < T/2 \end{cases}$ , find the Fourier series and sketch them.

c) Explain the characteristics of Uni Junction Transistor (UJT) and its use in the construction of relaxation oscillator. **(4+4+7)**

6. a) Explain the phenomenon of narrowing the channel in a FET. How does this affects the flow of carriers through it ?

b) Discuss the SCR characteristics and its use in the power control. **(8+7)**

## PART – IV

7. a) What are the inverting and non inverting operational amplifiers ? Give a suitable explanation why their outputs are in phase inversion to each other.

b) Explain the use of operational amplifier as a Comparator and Schmitt trigger. **(7+8)**

8. a) Discuss the voltage regulators as a three terminal and SIMPS Tristate devices.

b) What is the multivibrator ? Discuss the multivibrator as astable and mention its frequency response output. **(8+7)**



PART – V

9. Answer **any two** questions from following : **(2×5=10)**

a) Determine the packing efficiency and density of NaCl from the following data's

- i) radius of the  $\text{Na}^+$  ion =  $0.98 \text{ \AA}$ ,
- ii) radius of the  $\text{Cl}^-$  ion =  $1.81 \text{ \AA}$ ,
- iii) atomic mass of Na = 22.99 amu and
- iv) atomic mass of Cl = 35.45 amu.

b) The intrinsic carrier density at 300 K in silicon is  $1.5 \times 10^{16} / \text{cm}^3$ . If the electron and hole mobilities are  $0.13$  and  $0.05 \text{ m}^2 \text{ V}^{-1} \text{ S}^{-1}$  respectively. Calculate the conductivity of

- i) intrinsic silicon and
- ii) silicon containing 1 donor impurity atom per  $10^8$  silicon atom.

c) Explain about bipolar transistor differential amplifier.

d) Explain about the decoders and encoders.

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